

Shenzhen Zhongjian Nanfang Testing Co., Ltd.

Report No: CCISE180602001

FCC REPORT (GSM & WCDMA)

Applicant: NEXUS TELECOM SERVICES (HK) LIMITED

Address of Applicant: R112, 11/F Hollywood Plaza, Mangkok, Kowloon Hong Kong

Equipment Under Test (EUT)

Product Name: MOBILE PHONE

Model No.: GO404

Trade mark: GOMOBILE

FCC ID: 2AHDFGO404

FCC CFR Title 47 Part 2

Applicable standards: FCC CFR Title 47 Part 22 Subpart H

FCC CFR Title 47 Part 24 Subpart E

Date of sample receipt: 05 Jun., 2018

Date of Test: 05 Jun., to 24 Jul., 2018

Date of report issued: 24 Jul., 2018

Test Result: PASS*

* In the configuration tested, the EUT complied with the standards specified above.

Authorized Signature:



Bruce Zhang Laboratory Manager

This report details the results of the testing carried out on one sample. The results contained in this test report do not relate to other samples of the same product and does not permit the use of the CCIS product certification mark. The manufacturer should ensure that all products in series production are in conformity with the product sample detailed in this report.

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2. Version

Version No.	Date	Description
00	24 Jul., 2018	Original

Tested by: Mike DU Date: 24 Jul., 2018

Test Engineer

Reviewed by: Date: 24 Jul., 2018

Project Engineer



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4. Test Summary

Test Item	Section in CFR 47	Result
RF Exposure (SAR)	Part 1.1307 Part 2.1093	Pass (Please refer t SAR Report)
RF Output Power	Part 2.1046 Part 22.913 (a)(2) Part 24.232 (c)	Pass
Peak-to-Average Power Ratio	Part 24.232 (d)	Pass
Modulation Characteristics	Part 2.1047	Pass
99% & -26 dB Occupied Bandwidth	Part 2.1049 Part 22.917(b) Part 24.238(b)	Pass
Spurious Emissions at Antenna Terminal	Part 2.1051 Part 22.917 (a) Part 24.238 (a)	Pass
Field Strength of Spurious Radiation	Part 2.1053 Part 22.917 (a) Part 24.238 (a)	Pass
Out of band emission, Band Edge	Part 22.917 (a) Part 24.238 (a)	Pass
Frequency stability vs. temperature	Part 22.355 Part 24.235 Part 2.1055(a)(1)(b)	Pass
Frequency stability vs. voltage	Part 22.355 Part 24.235 Part 2.1055(d)(2)	Pass





5. General Information

5.1 Client Information

Applicant:	NEXUS TELECOM SERVICES (HK) LIMITED	
Address:	R112, 11/F Hollywood Plaza, Mangkok, Kowloon Hong Kong	
Manufacturer	NEXUS TELECOM SERVICES (HK) LIMITED	
Address:	R112, 11/F Hollywood Plaza, Mangkok, Kowloon Hong Kong	

5.2 General Description of E.U.T.

Product Name:	MOBILE PHONE
Model No.:	GO404
Operation Frequency range:	GSM 850: 824.20MHz-848.80MHz
	PCS1900: 1850.20MHz-1909.80MHz
	WCDMA Band V: 826.4MHz-846.6MHz
	WCDMA Band II: 1852.4 MHz-1907.6 MHz
Modulation type:	GSM/GPRS: GMSK, UMTS: QPSK
Antenna type:	Internal Antenna
Antenna gain:	GSM 850: -0.3 dBi
	PCS 1900: -0.7 dBi
	WCDMA Band V: -0.5 dBi
	WCDMA Band II: -0.7 dBi
Power supply:	Rechargeable Li-ion Battery DC3.7V-1300mAh
AC adapter:	Model: GO404
	Input: AC100-240V, 50/60Hz, 0.2A
	Output: DC 5.0V, 500mA





Operation Frequency List:

G	SM 850	PCS1900		
Channel	Frequency (MHz)	Channel	Frequency (MHz)	
128	824.20	512	1850.20	
129	824.40	513	1850.40	
189	836.40	660	1879.80	
190	836.60	661	1880.00	
191	836.80	662	1880.20	
250	848.60	809	1909.60	
251	848.80	810	1909.80	
WCD	MA Band V	WCDMA Band II		
Channel	Frequency (MHz)	Channel	Frequency (MHz)	
4132	826.40	9262	1852.40	
4133	826.60	9263	1852.60	
4182	836.40	9399	1879.80	
4183	836.60	9400	1880.00	
4184	836.80	9401	1880.20	
4232	846.40	9537	1907.40	
4233	846.60	9538	1907.60	

Regards to the operating frequency range over 10 MHz, the Lowest frequency, the middle frequency, and the highest frequency of channel were selected to perform the test, and the selected channel see below:

	GSM850		PCS1900			
Channel		Frequency(MHz)	Channel		Frequency(MHz)	
Lowest channel	128	824.20	Lowest channel	512	1850.20	
Middle channel	190	836.60	Middle channel	661	1880.00	
Highest channel	251	848.80	Highest channel 810		1909.80	
WCDMA Band V			WCDMA Band II			
Channel		Frequency(MHz)	Channel Frequ		Frequency(MHz)	
Lowest channel	4132	826.40	Lowest channel	9262	1852.40	
Middle channel	4183	836.60	Middle channel	9400	1880.00	
Highest channel	ghest channel 4233		Highest channel	9538	1907.60	

5.3 Test modes

Operating Environmen	Operating Environment:		
Temperature:	Normal: 15°C ~ 35°C, Extreme: -30°C ~ +50°C		
Humidity:	20 % ~ 75 % RH		
Atmospheric Pressure:	1008 mbar		
Voltage:	Nominal: 3.7Vdc, Extreme: Low 3.5 Vdc, High 4.2 Vdc		
Test mode:			
GSM mode	Keep the EUT communication with simulated station in GSM mode		
GPRS mode	Keep the EUT communication with simulated station in GPRS mode		
RMC mode	Keep the EUT communication with simulated station in RMC mode		
HSDPA	Keep the EUT communication with simulated station in HSDPA mode		
HSUPA	Keep the EUT communication with simulated station in HSUPA mode		
D I TI . FUT I I	Develop The FUT has been feefed by been of a contract of the configuration of the contract of		

Remark: The EUT has been tested under continuous transmitting mode. Channel Low, Mid and High for each type band with rated data rate were chosen for full testing. The field strength of spurious radiation emission was measured as EUT stand-up position (H mode) and lie down position (E1, E2 mode) for these modes with power adaptor, earphone and Data cable. Just the worst case position (H mode) shown in report.

5.4 Description of Support Units

Test Equipment	Manufacturer	Model No.	Serial No.	
Simulated Station	Anritsu	MT8820C	6201026545	

5.5 Measurement Uncertainty

Parameters	Expanded Uncertainty
Radiated Emission (9kHz ~ 30MHz)	±2.76 dB (k=2)
Radiated Emission (30MHz ~ 1000MHz)	±4.28 dB (k=2)
Radiated Emission (1GHz ~ 18GHz)	±5.72 dB (k=2)
Radiated Emission (18GHz ~ 40GHz)	±2.88 dB (k=2)

5.6 Laboratory Facility

The test facility is recognized, certified, or accredited by the following organizations:

FCC - Registration No.: 727551

Shenzhen Zhongjian Nanfang Testing Co., Ltd. has been accredited as a testing laboratory by FCC (Federal Communications Commission). The Registration No. is 727551.

• IC - Registration No.: 10106A-1

The 3m Semi-anechoic chamber of Shenzhen Zhongjian Nanfang Testing Co., Ltd. has been Registered by Certification and Engineering Bureau of Industry Canada for radio equipment testing with Registration No.: 10106A-1.

CNAS - Registration No.: CNAS L6048

Shenzhen Zhongjian Nanfang Testing Co., Ltd. is accredited to ISO/IEC 17025:2005 General Requirements for the Competence of Testing and Calibration laboratories for the competence of testing. The Registration No. is CNAS L6048.

A2LA - Registration No.: 4346.01

This laboratory is accredited in accordance with the recognized International Standard ISO/IEC 17025:2005 General requirements for the competence of testing and calibration laboratories. The test scope can be found as below link: https://portal.a2la.org/scopepdf/4346-01.pdf

Shenzhen Zhongjian Nanfang Testing Co., Ltd.
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Telephone: +86 (0) 755 23116366



5.7 Laboratory Location

Shenzhen Zhongjian Nanfang Testing Co., Ltd.

Address: No. B-C, 1/F., Building 2, Laodong No.2 Industrial Park, Xixiang Road,

Bao'an District, Shenzhen, Guangdong, China Tel: +86-755-23118282, Fax: +86-755-23116366

Email: info@ccis-cb.com, Website: http://www.ccis-cb.com

5.8 Test Instruments list

Test Equipment	Manufacturer	Model No.	Serial No.	Cal. Date (mm-dd-yy)	Cal. Due date (mm-dd-yy)
3m SAC	SAEMC	9m*6m*6m	966	07-22-2017	07-21-2020
BiConiLog Antenna	SCHWARZBECK	VULB9163	497	03-16-2018	03-15-2019
Biconical Antenna	SCHWARZBECK	VUBA9117	359	06-22-2017	06-21-2020
Horn Antenna	SCHWARZBECK	BBHA9120D	916	03-16-2018	03-15-2019
Horn Antenna	SCHWARZBECK	BBHA9120D	1805	06-22-2017	06-21-2020
EMI Test Software	AUDIX	E3	6.110919b	N/A	N/A
Pre-amplifier	HP	8447D	2944A09358	03-07-2018	03-06-2019
Pre-amplifier	CD	PAP-1G18	11804	03-07-2018	03-06-2019
Spectrum analyzer	Rohde & Schwarz	FSP30	101454	03-07-2018	03-06-2019
EMI Test Receiver	Rohde & Schwarz	ESRP7	101070	03-07-2018	03-06-2019
Spectrum Analyzer	Agilent	N9020A	MY50510123	11-10-2017	11-09- 2018
Signal Generator	Rohde & Schwarz	SMX	835454/016	03-07-2018	03-06-2019
Signal Generator	R&S	SMR20	1008100050	03-07-2018	03-06-2019
RF Switch Unit	MWRFTEST	MW200	N/A	N/A	N/A
Cable	ZDECL	Z108-NJ-NJ-81	1608458	03-07-2018	03-06-2019
Cable	MICRO-COAX	MFR64639	K10742-5	03-07-2018	03-06-2019
Cable	SUHNER	SUCOFLEX100	58193/4PE	03-07-2018	03-06-2019
DC Power Supply	XinNuoEr	WYK-10020K	1409050110020	10-31-2017	10-30-2018
Temperature Humidity Chamber	HengPu	HPGDS-500	20140828008	09-24-2017	09-23-2018
Simulated Station	Rohde & Schwarz	CMW500	140493	06-24-2017	06-23-2018
Simulated Station	Notice & Scriwarz	CIVIVVOO	140493	06-24-2018	06-23-2019



6. Test results

6.1 Conducted Output Power

- Conducted Catpati		
Test Requirement:	FCC part 22.913(a)(2), FCC part 24.232(c)	
Test Method:	ANSI/TIA-603-D 2010	
Limit:	GSM 850: 7W, PCS 1900: 2W WCDMA Band V: 7W, WCDMA Band II: 2W	
Test setup:	System simulator ATT EUT	
Test Procedure:	The transmitter output was connected to a calibrated attenuator, the other end of which was connected to the simulated station. Transmitter output power was read off in dBm.	
Test Instruments:	Refer to section 5.8 for details	
Test mode:	Refer to section 5.3 for details	
Test results:	Passed	





Measurement Data:

Measurement Bata.				
	Burs	st Average power (dE	Bm)	
EUT Mode	128	190	251	Limit(dBm)
	824.20MHz	836.60MHz	848.80MHz	
GSM 850	32.78	32.74	32.56	
GPRS 850 (1 Uplink slot)	32.81	32.79	32.59	
GPRS 850 (2 Uplink slot)	31.00	30.86	30.73	38.45
GPRS 850 (3 Uplink slot)	29.41	29.28	29.07	
GPRS 850 (4 Uplink slot)	27.79	27.66	27.47	
	Burs			
EUT Mode	512	661	810	Limit(dBm)
	1850.20MHz	1880.00MHz	1909.80MHz	
PCS 1900	29.93	30.12	30.13	
GPRS 1900 (1 Uplink slot)	29.99	30.20	30.18	
GPRS 1900 (2 Uplink slot)	27.33	27.61	27.88	33.00
GPRS 1900 (3 Uplink slot)	25.86	26.11	26.42	
GPRS 1900 (4 Uplink slot)	23.99	24.24	24.57	





		Burst	t Average power (c	IBm)	
EUT Mode	e	4132	4183	4233	Limit(dBm)
		826.40MHz	836.60MHz	846.60MHz	, ,
	Subtest 1	21.77	22.65	21.91	
LIMTO OFO LICEDA	Subtest 2	21.60	22.20	21.69	
UMTS 850 HSDPA	Subtest 3	21.16	21.44	21.28	
	Subtest 4	21.21	21.21	21.17	
	Subtest 1	21.59	22.31	21.70	
	Subtest 2	21.70	22.59	21.80	38.45
UMTS 850 HSUPA	Subtest 3	21.31	21.70	21.19	
	Subtest 4	21.65	22.59	21.80	
	Subtest 5	21.25	21.96	21.39	
UMTS 850 RMC	12.2kbps	23.03	23.11	23.21	
UMTS 850 AMR	12.2kbps	23.03	23.08	23.15	
		Burst Average power (dBm)			
EUT Mode	Э	9262	9400	9538	Limit(dBm)
		1852.40MHz	1880.00MHz	1907.60MHz	
	Subtest 1	21.99	22.38	21.57	
UMTS 1900 HSDPA	Subtest 2	21.67	22.16	21.13	
OWITS 1900 FISDEA	Subtest 3	21.34	21.82	20.91	
	Subtest 4	21.13	21.58	20.80	
	Subtest 1	21.77	22.19	21.38	
	Subtest 2	21.83	22.27	21.51	33.00
UMTS 1900 HSUPA	Subtest 3	21.40	21.68	21.00	
	Subtest 4	21.83	22.25	21.45	
	Subtest 5	21.54	22.06	21.19	
UMTS 1900 RMC	12.2kbps	23.41	23.14	23.01	
UMTS 1900 AMR	12.2kbps	23.21	23.08	22.94	



6.2 Occupy Bandwidth

Test Requirement:	FCC part 22.917(b), FCC part 24.238(b)
Test Method:	ANSI/TIA-603-D 2010
Test setup:	System simulator Splitter ATT EUT Spectrum Analyzer
Test Procedure:	 The EUT's output RF connector was connected with a short cable to the spectrum analyzer RBW was set to about 1% of emission BW, VBW= 3 times RBW. -26dBc display line was placed on the screen (or 99% bandwidth), the occupied bandwidth is the delta frequency between the two points where the display line intersects the signal trace.
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed





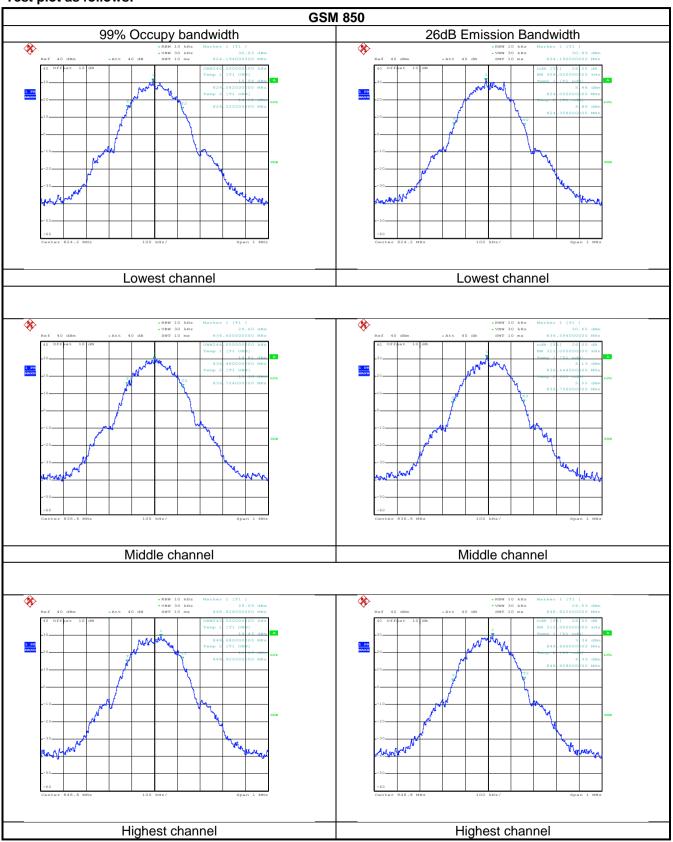
Measurement Data:

EUT Mode	Channel	Frequency (MHz)	99% Occupy bandwidth (kHz)	-26dB bandwidth (kHz)
	128	824.2	240	308
GSM 850	190	836.6	244	312
	251	848.8	242	312
	512	1850.2	248	314
PCS 1900	661	1880.0	240	318
	810	1909.8	246	320
LIMTO OFO	4132	826.4	4160	4680
UMTS 850 12.2k RMC	4183	836.6	4200	4760
12.2K KIVIO	4233	846.6	4180	4680
	9262	1852.4	4160	4720
UMTS 1900 12.2k RMC	9400	1880.0	4180	4680
12.2K KIVIC	9538	1907.6	4160	4700

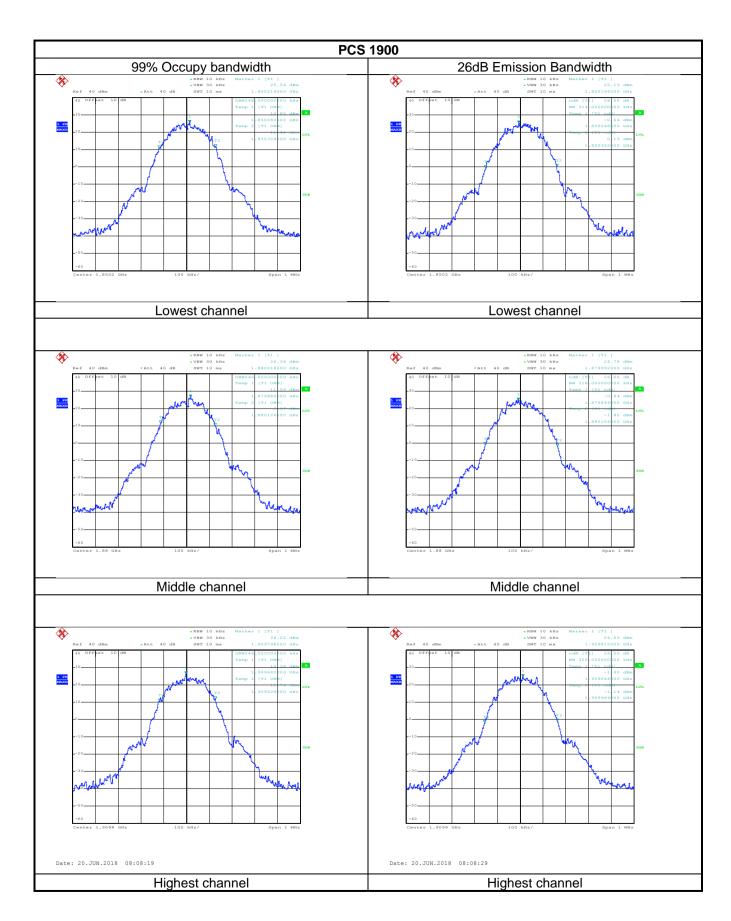
Note: GSM & GPRS use the same modulation technical (GMSK), and with the same channels, so the 99% OBW and the -26dB of GPRS not performed.



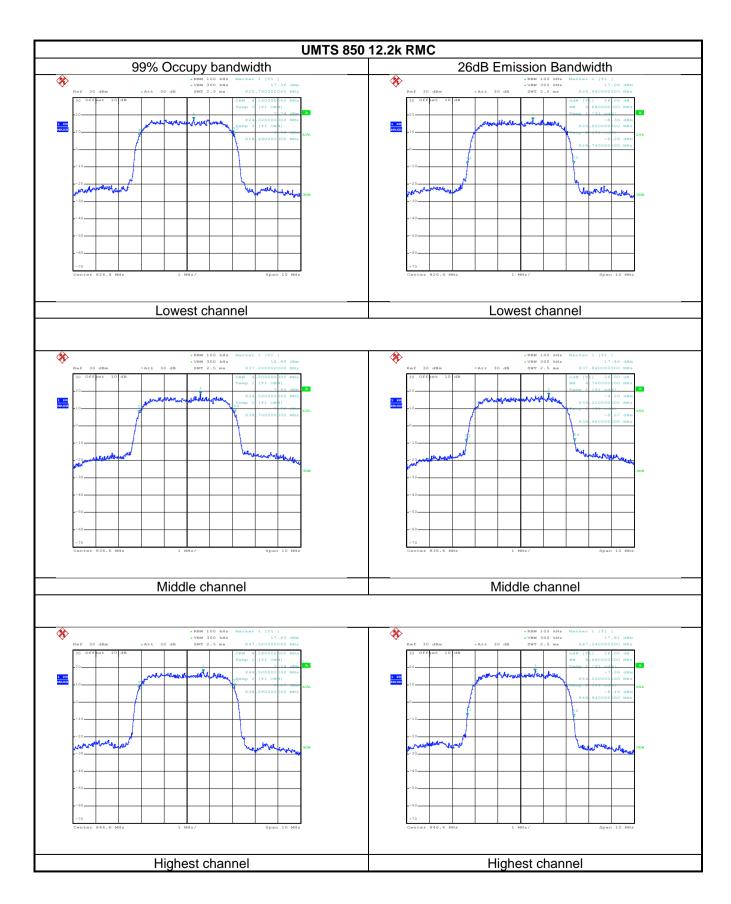
Test plot as follows:



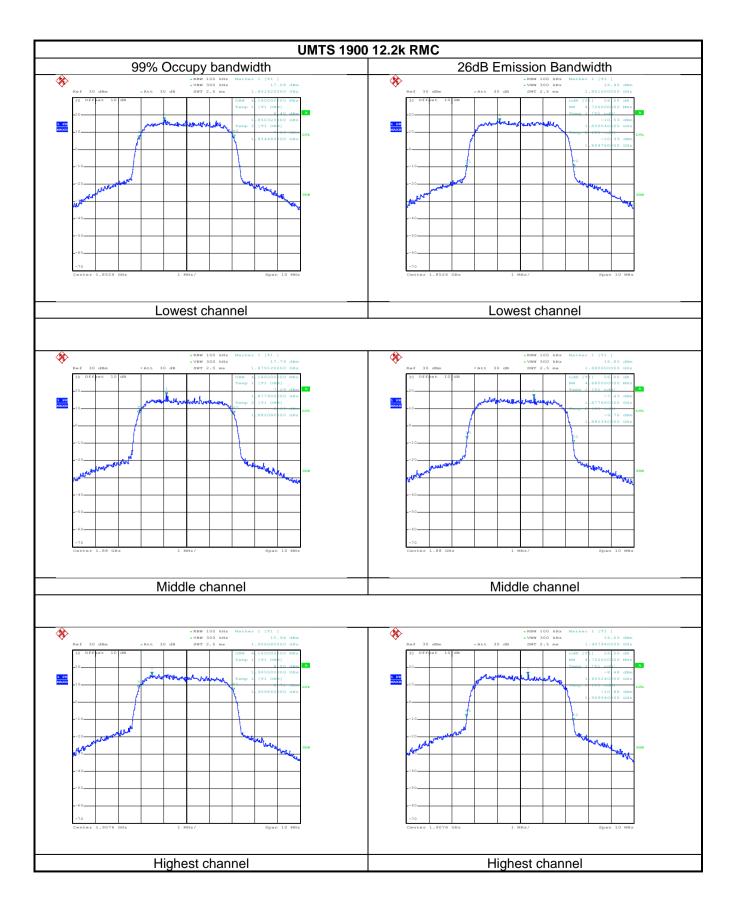














6.3 Peak-to-Average Power Ratio

Test Requirement:	FCC part 24.232(d)
Test Method	ANSI/TIA-603-D 2010
Limit:	The peak-to-average ratio (PAR) of the transmission may not exceed 13 dB.
Test setup:	System simulator Spectrum Analyzer
Test Procedure:	 The RF output of the transceiver was connected to a spectrum analyzer through appropriate attenuation. Set the CCDF option in spectrum analyzer, RBW ≥ OBW, Set the EUT working in highest power level, measured and recorded the 0.1% as PAPR level. Repeat step 1~3 at other frequency and modulations.
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed

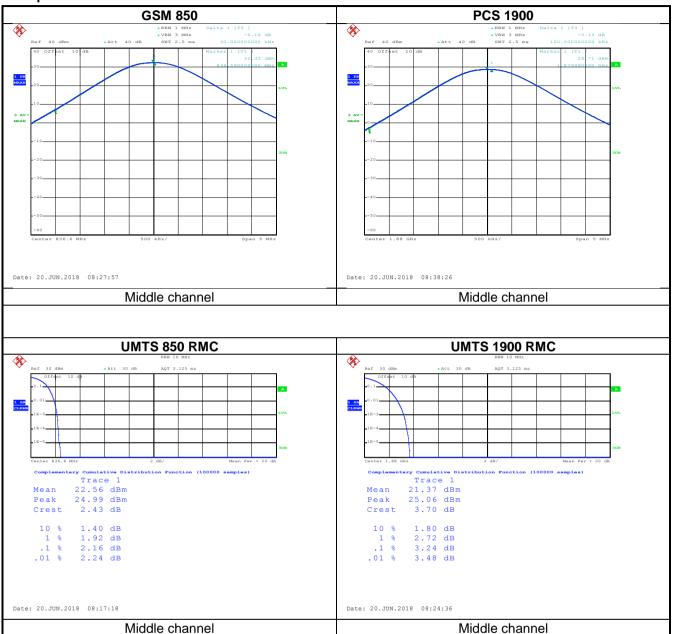
Measurement Data:

Modulation	Test channel	PAPR
GSM 850	190	0.16
PCS 1900	661	0.13
UMTS 850 RMC	4183	2.16
UMTS 1900 RMC	9400	3.24





Test plots as below:





6.4 Modulation Characteristic

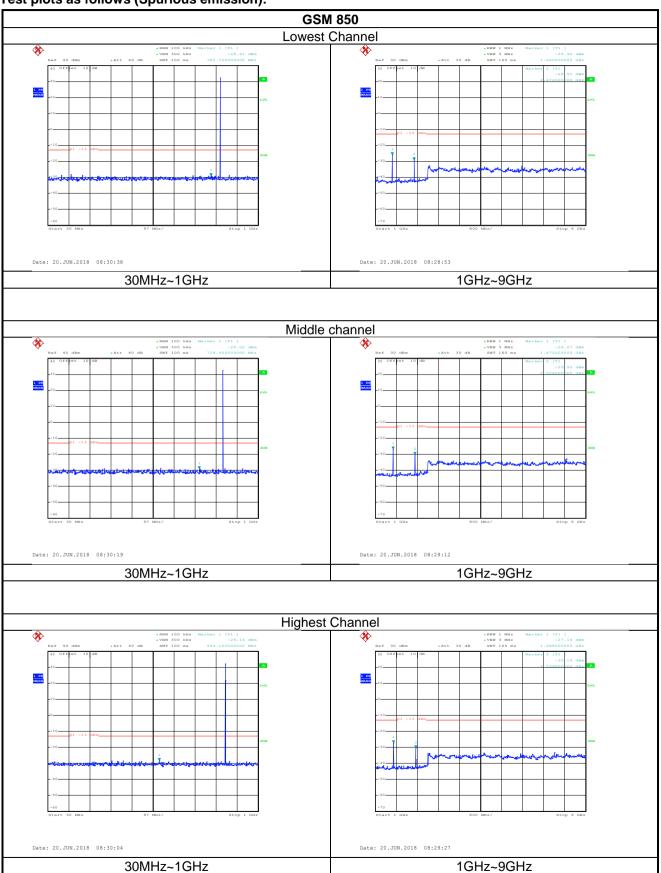
According to FCC § 2.1047(d), Part 22H & 24E there is no specific requirement for digital modulation, therefore modulation characteristic is not presented.

6.5 Out of band emission at antenna terminals

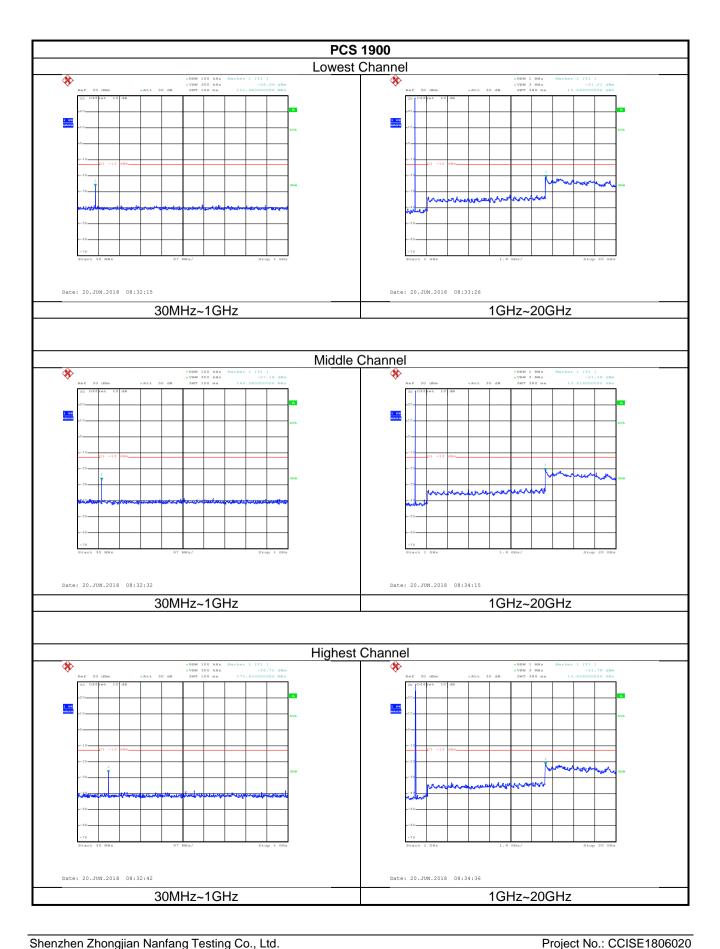
Test Requirement:	FCC part 22.917(a), FCC part 24.238(a)
Test Method:	ANSI/TIA-603-D 2010
Limit:	-13dBm
Test setup:	System simulator Splitter ATT EUT
	Spectrum Analyzer
Test Procedure:	 The RF output of the transceiver was connected to a spectrum analyzer through appropriate attenuation. The resolution bandwidth of the spectrum analyzer was set at 100 kHz when below 1GHz, 1MHz when above 1 GHz; sufficient scans were taken to show the out of band Emissions if any up to 10th harmonic. For the out of band: Set the RBW=100 kHz, VBW=300 kHz when below 1 GHz, RBW =1 MHz, VBW=3 MHz when above 1 GHz, Start=30MHz, Stop= 10th harmonic. Band Edge Requirements: In the 1 MHz bands immediately outside and adjacent to the frequency block, a resolution bandwidth of at least 1 percent of the emission bandwidth of the fundamental emission of the transmitter may be employed to measure the out of band Emissions.
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed



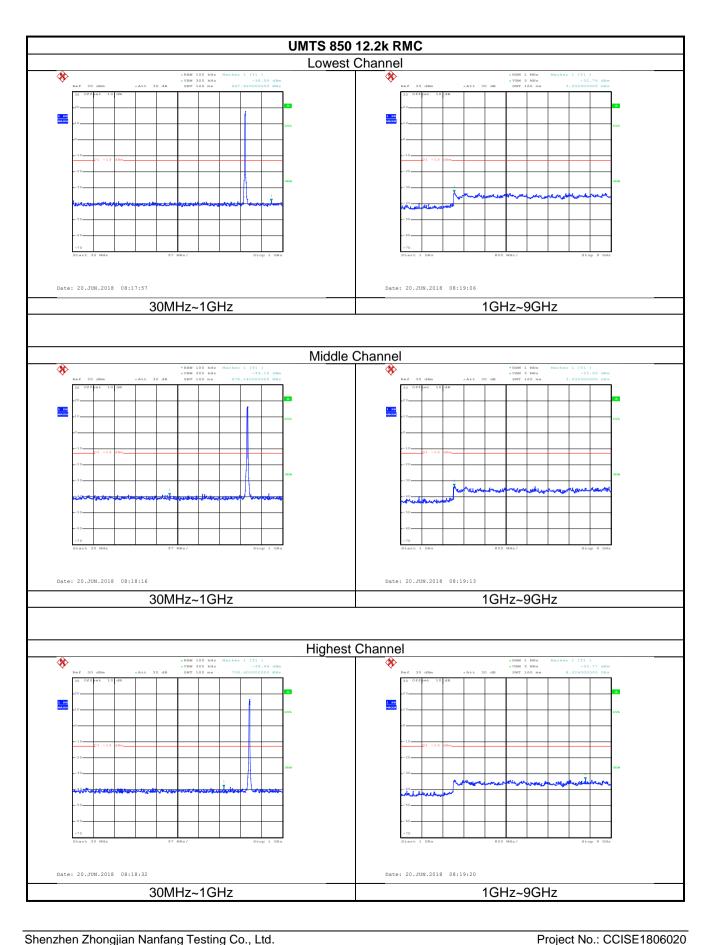
Test plots as follows (Spurious emission):



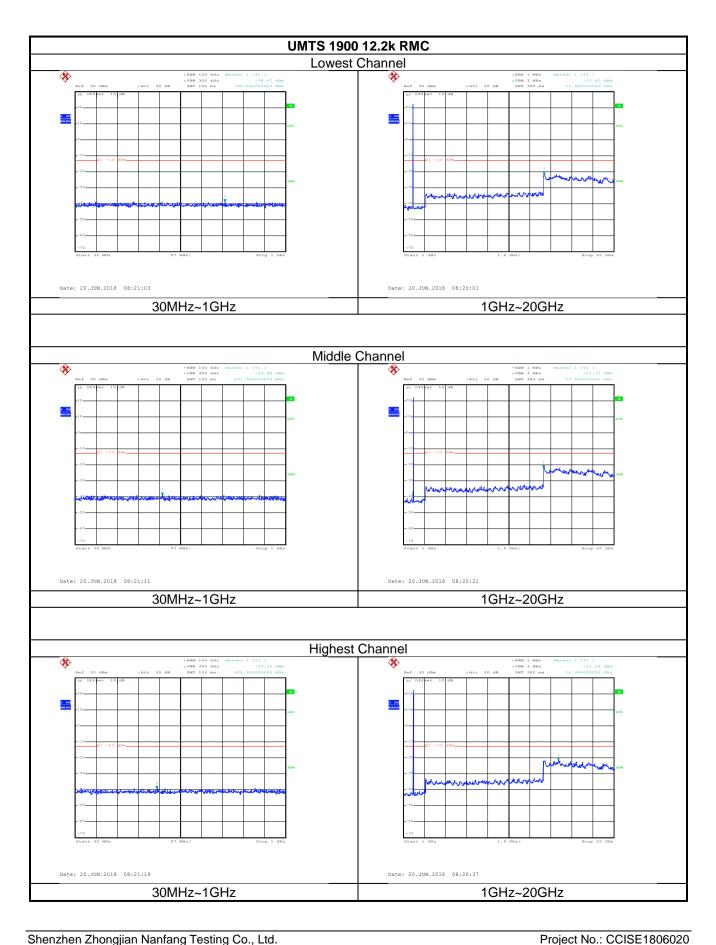








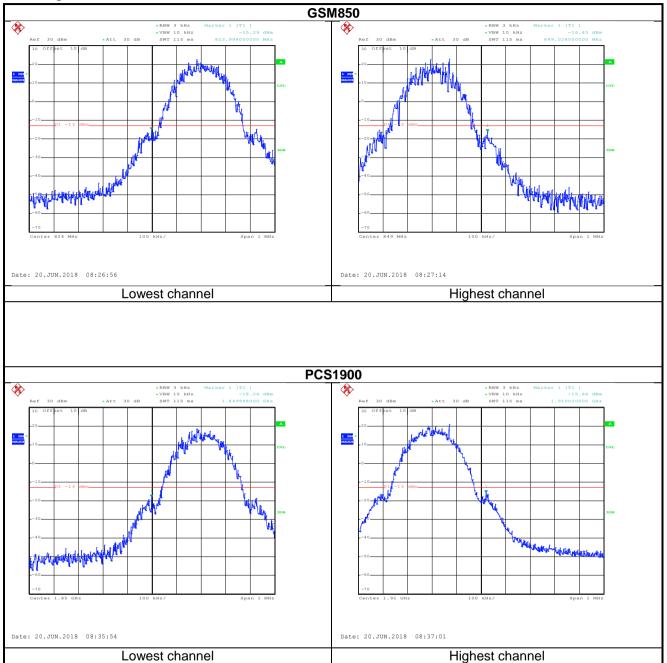




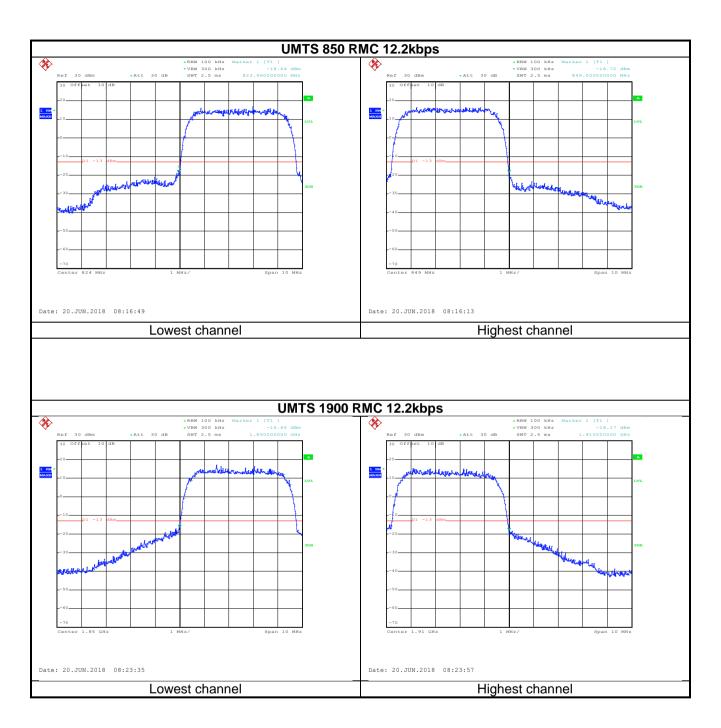




Band edge emission:









6.6 ERP, EIRP Measurement

Test Dequirement	
Test Requirement:	FCC part 22.913(a)(2), FCC part 24.232(c)
Test Method:	ANSI/TIA-603-D 2010
Limit:	GSM850 7W: ERP, PCS1900 2W: EIRP
Took ook in	UMTS 850: 7W ERP, UMTS1900: 2W EIRP
Test setup:	Above 1GHz Above 1GHz Horn Antenna Tower
	Ground Reference Plane Test Receiver Angular Controller
Test Procedure:	 The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer. During the measurement, the EUT was communication with the station. The highest emission was recorded with the rotation of the turntable and the lowering of the test antenna from 4m to 1m. The reading was recorded and the field strength (E in dBuV/m) was calculated. ERP in frequency band 824.2 –848.80.8MHz were measured using a substitution method. The EUT was replaced by dipole antenna connected, the S.G. output was recorded and ERP was calculated as follows: ERP = S.G. output (dBm) + Antenna Gain (dBd) – Cable Loss (dB) EIRP in frequency band 1850.2 –1909.8MHz were measured using a substitution method. The EUT was replaced by or born entennal contents and the part and the
	substitution method. The EUT was replaced by or horn antenna connected, the S.G. output was recorded and EIRP was calculated as follows: EIRP = S.G. output (dBm) + Antenna Gain (dBi) – Cable Loss (dB) 5. The worst case was relating to the conducted output power.
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed





Measurement Data (worst case):

moacaroment Bata	, ,					
EUT mode	Channel	EUT Pol.	Antenna Pol.	ERP(dBm)	Limit (dBm)	Result
GSM850	128	Ц	V	21.33		
GSIVIOSU	120	П	Н	23.29	20 45	Door
UMTS 850 12.2k	4400		V	19.57	38.45	Pass
RMC	4183	Н	Н	16.21		
EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result
PCS1900	810	Н	V	24.56		
PC31900	810	П	Н	22.12	22	Door
UMTS 1900	0262	Ш	V	20.08	33	Pass
12.2k RMC	9262	Н	Н	22.67		



6.7 Field strength of spurious radiation measurement

Test Requirement:	FCC part 22.917(a), FCC part 24.238(a)
Test Method:	ANSI/TIA-603-D 2010
Limit:	-13dBm
Limit: Test setup:	Below 1GHz Antenna Tower Test Receiver Ground Reference Plane
Test Procedure:	 The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations. The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emission was identified, the power of the emission was determined using the substitution method. The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency. ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) – Cable Loss (dB)
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details.
Test results:	Passed





Measurement Data (worst case):

		GSM850		
		Lowest channel		
Fragues av (MILE)	Spurious	Emission	Limeit (alDine)	Dooult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
1648.40	Vertical	-37.42		Pass
2472.60	V	-34.53	-13.00	
3296.80	V	-39.49		
1648.40	Horizontal	-32.49		
2472.60	Н	-35.21	-13.00	Pass
3296.80	Н	-39.28		
·		Middle channel		
Fragues av (MIII-)	Spurious	Emission	Limeit (alDune)	Result
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	
1673.20	Vertical	-33.42		Pass
2509.80	V	-35.11	-13.00	
3346.40	V	-38.32		
1673.20	Horizontal	-32.05		
2509.80	Н	-35.13	-13.00	Pass
3346.40	Н	-40.23		
		Highest channel		
	Spurious	Spurious Emission		Dooult
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
1697.60	Vertical	-34.52		
2546.40	V	-41.69	-13.00	Pass
3395.20	V	-38.16]	
1697.60	Horizontal	-32.48		
2546.40	Н	-20.36	-13.00	Pass
3395.20	Н	-41.91]	

Remark:

^{1.} The emission levels of below 1 GHz are very lower than the limit and not show in test report.





		PCS1900		
		Lowest channel		
Fraguenov (MIII-)	Spurious	Emission	Limit (dDm)	D !!
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3700.40	Vertical	-43.21	42.00	
5550.60	V	-40.63	-13.00	Pass
3700.40	Horizontal	-45.29	42.00	Dana
5550.60	Н	-41.08	-13.00	Pass
·		Middle channel		
Francisco (MIII-)	Spurious	Emission	on Limit (dD ::)	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3760.00	Vertical	-45.11	40.00	Pass
5640.00	V	-40.87	-13.00	
3760.00	Horizontal	-47.96	42.00	Dana
5640.00	Н	-41.52	-13.00	Pass
		Highest channel		
Francisco (MIII-)	Spurious	Emission	Line it (dDne)	Daguit
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result
3819.60	Vertical	-44.78	42.00	Door
5729.40	V	-40.36	-13.00	Pass
3819.60	Horizontal	-46.37	42.00	Dans
5729.40	Н	-41.24	-13.00	Pass

The emission levels of below 1 GHz are very lower than the limit and not show in test report. 1.





	WCDI	MA BAND V 12.2k RN	ИС		
		Lowest channel			
Гто су (МП I=)	Spurious Emission		Limit (dDm)	D 11	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
1652.80	Vertical	-39.25			
2479.20	V	-30.56	-13.00	Pass	
3305.60	V	-49.22			
1652.80	Horizontal	-45.32			
2479.20	Н	-36.73	-13.00	Pass	
3305.60	Н	-48.51			
		Middle channel			
Fragues av (MIII-)	Spurious	Emission	Limit (dDm)	Dooult	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
1673.20	Vertical	-49.87			
2509.80	V	-30.26	-13.00	Pass	
3346.40	V	-49.32			
1673.20	Horizontal	-46.36			
2509.80	Н	-40.41	-13.00	Pass	
3346.40	Н	-49.03			
		Highest channel			
Frequency (MHz)	Spurious Emission		Limit (dBm)	Result	
Frequency (MHZ)	Polarization	Level (dBm)	Limit (dbin)	Kesuii	
1693.20	Vertical	-46.54			
2539.80	V	-48.43	-13.00	Pass	
3386.40	V	-49.25			
1693.20	Horizontal	-39.28			
2539.80	Н	-48.31	-13.00	Pass	
3386.40	Н	-49.17			
Remark:					

^{1.} The emission levels of below 1 GHz are very lower than the limit and not show in test report.





	WCD	MA Band II 12.2k RM	С		
		Lowest channel			
Fraguenov (MIII-)	Spurious Emission		Limit (dDm)	D !!	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3704.80	Vertical	-37.22	40.00	Door	
5557.20	V	-30.43	-13.00	Pass	
3704.80	Horizontal	-36.85	42.00	Dans	
5557.20	Н	-28.61	-13.00	Pass	
·		Middle channel			
Fragues av (MIII-)	Spurious Emission		Lind (ID)	Danult	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3760.00	Vertical	-39.72	40.00	Davis	
5640.00	V	-28.25	-13.00	Pass	
3760.00	Horizontal	-39.17	42.00	Door	
5640.00	Н	-27.34	-13.00	Pass	
		Highest channel			
Crocupacy (MIII-)	Spurious Emission		Line it (dDne)	D !!	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3815.20	Vertical	-37.52	42.00	Dane	
5722.80	V	-30.85	-13.00	Pass	
3815.20	Horizontal	-38.96	12.00	Door	
5722.80	Н	-26.43	-13.00	Pass	

The emission levels of below 1 GHz are very lower than the limit and not show in test report. 1.



6.8 Frequency stability V.S. Temperature measurement

Test Requirement:	FCC Part 22.355, FCC Part 24.235, FCC Part 2.1055(a)(1)(b)
Test Method:	ANSI/TIA-6-3-D 2010
Limit:	±2.5 ppm
Test setup:	SS EUT Divider Temperature & Humidity Chamber Power Source
Test procedure:	 The equipment under test was connected to an external DC power supply and input rated voltage. RF output was connected to a frequency counter or spectrum analyzer via feed through attenuators. The EUT was placed inside the temperature chamber. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and measure EUT 25°C operating frequency as reference frequency. Turn EUT off and set the chamber temperature to -30°C. After the temperature stabilized for approximately 30 minutes recorded the frequency. Repeat step measure with 10°C increased per stage until the highest temperature of +50°C reached
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed





Measurement Data (the worst channel):

Refe	erence Frequency: GS	SM850 Middle	channel=190 cha	nnel=836.6MHz	
Power supplied	Temperature (°C)	Frequency error		Limit (nnm)	D !!
(Vdc)	remperature (C)	Hz	ppm	Limit (ppm)	Result
	-30	190	0.227110		Pass
	-20	127	0.151805		
	-10	178	0.212766		
	0	150	0.179297		
3.70	10	123	0.147024	±2.5	
	20	114	0.136266		
	30	105	0.125508		
	40	146	0.174516	-	
	50	149	0.178102		
Refe	erence Frequency: PC	S1900 Middl	e channel=661 cha	nnel=1880MHz	
Power supplied	Temperature (°C)	Freq	uency error	Limit (ppm)	Result
(Vdc)	remperature (C)	Hz	ppm	сини (ррин)	
	-30	187	0.099468		
	-20	165	0.087766		Pass
	-10	132	0.070213		
3.70	0	171	0.090957	±2.5	
	10	175	0.093085		
	20	136	0.072340		
	30	125	0.066489		
	40	126	0.067021		
	50	107	0.056915	7	





Power supplied (Vdc)	Temperature (°C)	Fred	quency error	12-26 (22-22)	Result
		Hz	ppm	Limit (ppm)	
	-30	191	0.228305		Pass
	-20	123	0.147024		
	-10	136	0.162563		
	0	171	0.204399		
3.70	10	180	0.215157	±2.5	
	20	145	0.173321		
	30	102	0.121922	_	
	40	114	0.136266		
	50	120	0.143438		
Reference Fre	quency: WCDMA BAN	ND II 12.2k R	MC Middle channel	=9400 channel=1	880MHz
Power supplied	Temperature (°C)	Frequency error		Limit (ppm)	Result
(Vdc)	remperature (c)	Hz	ppm	Еппі (рріп)	Nesult
	-30	198	0.105319		Pass
	-20	165	0.087766		
	-10	177	0.094149		
	0	132	0.070213	±2.5 Pa	
3.70	10	151	0.080319		
	20	102	0.054255		
	30	145	0.077128		
	40	118	0.062766		
	50	126	0.067021	1	



6.9 Frequency stability V.S. Voltage measurement

Test Requirement:	FCC Part 22.355, FCC Part 24.235, FCC Part 2.1055(d)(2)
Test Method:	ANSI/TIA-603-D 2010
Limit:	±2.5ppm
Test setup:	SS EUT Divider Temperature & Humidity Chamber Power Source
Test procedure:	 Set chamber temperature to 25°C. Use a variable DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency. Reduce the input voltage to specify extreme voltage variation (+/-15%) and endpoint, record the maximum frequency change.
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed





Measurement Data (the worst channel):

Referen	ce Frequency: GSM850	Middle cha	nnel=190 channe	el=836.6MHz	
Tomporature (°C)	Power supplied	Frequency error		11	5 11
Temperature (°C)	(Vdc)	Hz	ppm	Limit (ppm)	Result
	4.20	98	0.117141	±2.5	
25	3.70	57	0.068133		Pass
	3.50	90	0.107578		
Referen	ce Frequency: PCS190	0 Middle cha	nnel=661 chann	el=1880MHz	
Townsorotors (°C)	Power supplied	Frequ	ency error	Limit (none)	Daniell
Temperature (℃)	(Vdc)	Hz	ppm	Limit (ppm)	Result
	4.20	85	0.045213	±2.5	Pass
25	3.70	90	0.047872		
	3.50	67	0.035638		
Reference Freq	uency: UMTS 850 12.2	k RMC Midd	le channel=4183	channel=836.6MF	łz
Tomporature (°C)	Power supplied	Frequency error		Limit (name)	Daguilt
Temperature (℃)	(Vdc)	Hz	ppm	Limit (ppm)	Result
	4.20	88	0.105188		
25	3.70	79	0.094430	±2.5	Pass
	3.50	60	0.071719		
Reference Freq	uency: UMTS 1900 12.2	2k RMC Mide	dle channel=9400	channel=1880Ml	Ηz
Tomporature (°C)	Power supplied	Frequency error		Lineit (none)	Descrit
Temperature (℃)	(Vdc)	Hz	ppm	Limit (ppm)	Result
	4.20	80	0.042553		
25	3.70	96	0.051064	±2.5	Pass
	3.50	84	0.044681	1	